

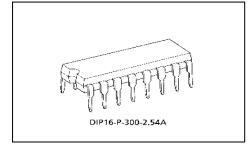
TOSHIBA BiCD Integrated Circuit Silicon Monolithic

# **TB67S111PG**

## Full parallel controlled solenoid driver / unipolar motor driver

The TB67S111PG is a solenoid driver /unipolar motor driver for full parallel input.

Using the BiCD process, the power supply voltage of  $45~\rm{V}$ , the output voltage of  $80~\rm{V}$ , and the output current of  $1.5~\rm{A/ch}$  (absolute maximum rating) are realized.



Weight: 1.11 g (typ.)

- **Features**
- Capable of driving up to four solenoids simultaneously. (4-ch sink driver)
- Capable of driving a unipolar stepping motor with a single chip.
- Built-in over current detection (automatic return / time control) at each output.
- · Built-in thermal shutdown detection (automatic return / time control), which detects errors of the whole device.
- Output (ERR) pin for thermal shutdown signal.

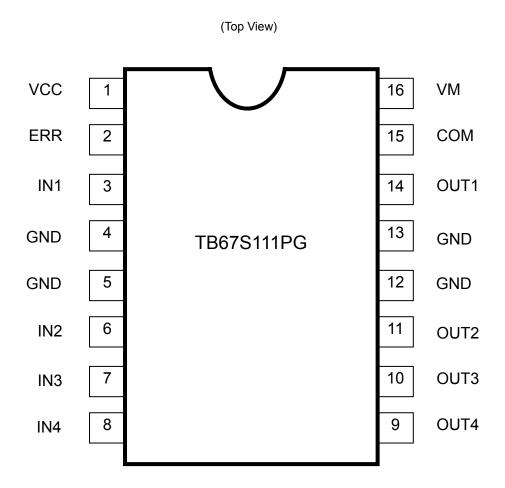
· BiCD integrated circuit silicon monolithic.

- Built-in output MOSFET for low ON resistance (0.25  $\Omega$  (typ.)).
- High voltage and large current (as for specifications, please refer to the absolute maximum ratings and operation ranges).
- Built-in abnormal detection functions (thermal shutdown detection (TSD), over current detection (ISD), and undervoltage detection (POR)).
- Built-in VCC regulator for internal circuit control, capable of being used as the pull-up point of an error output function.

Note: Please be careful about the thermal conditions during use.



# **Pin Assignment**

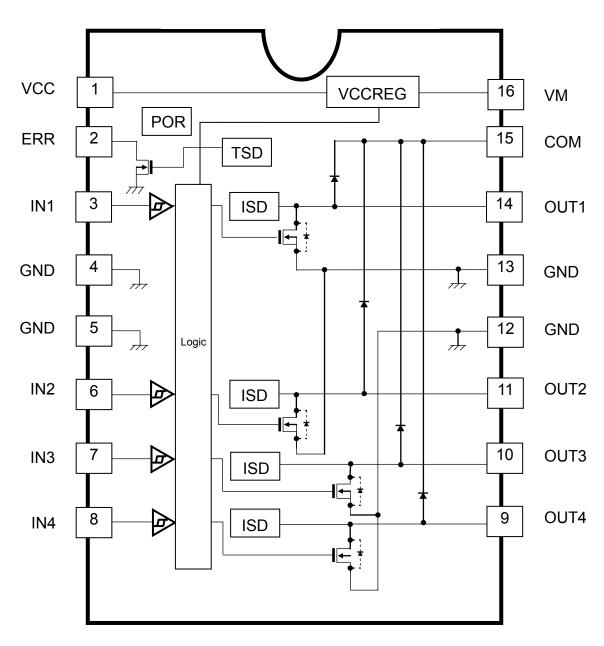


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## **Block Diagram**

(Top View)



Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

#### IC considerations

All the grounding wires of the device must run on the solder mask on the PCB and be externally terminated at only one point. Also, a grounding method should be considered for efficient heat dissipation.

Careful attention should be paid to the layout of the output, VM and GND traces, to avoid short circuits across output pins or to the power supply or ground. If such a short circuit occurs, the device may be permanently damaged. Also, the utmost care should be taken for pattern designing and implementation of the device since it has power supply pins (VM, OUT, GND, etc.) through which a particularly large current may run. If these pins are wired incorrectly, an operation error may occur or the device may be destroyed.

The logic input pins must also be wired correctly. Otherwise, the device may be damaged owing to a current running through the IC that is larger than the specified current. Careful attention should be paid for IC pattern design and mounting method.



# **Pin Function Description**

Function description (Pin No. 1 to 16)

Pin No.	Pin name	Function
1	VCC	Voltage monitor pin for internal regulator
2	ERR	Output pin for thermal shutdown signal
3	IN1	OUT1 output control pin
4	GND	GND pin
5	GND	GND pin
6	IN2	OUT2 output control pin
7	IN3	OUT3 output control pin
8	IN4	OUT4 output control pin
9	OUT4	Output pin 4
10	OUT3	Output pin 3
11	OUT2	Output pin 2
12	GND	GND pin
13	GND	GND pin
14	OUT1	Output pin 1
15	COM	COM pin
16	VM	Connection pin for motor power supply

<sup>\*</sup> All the grounding wires of the device must run on the solder mask on the PCB and be externally terminated at only one point. Also, a grounding method should be considered for efficient heat dissipation.



# Input / Output Equivalent Circuit

Pin name	Input / output signal	Equivalent circuit
IN1 IN2 IN3 IN4	Digital input (VIH/VIL)  VIH: 2.0 V (min) to 5.5 V (max)  VIL: 0 V (min) to 0.8 V (max)	Logic input pin Cy 00 777
ERR	Digital output VOD(L) (Pull-up resistance: $10 \text{ k}\Omega$ to $100 \text{ k}\Omega$ )	GND M
VCC	VCC voltage range 4.75 V (min) to 5.0 V (typ.) to 5.25 V (max)	VCC 🛛
OUT1 OUT2 OUT3 OUT4 GND COM	VM voltage operation range 10 V (min) to 40 V (max)  OUT pin withstanding voltage 10 V (min) to 80 V (max)	Output pin Output pin

<sup>\*</sup> The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.



# **Functional Description**

Relation between logic inputs and output MOSFET

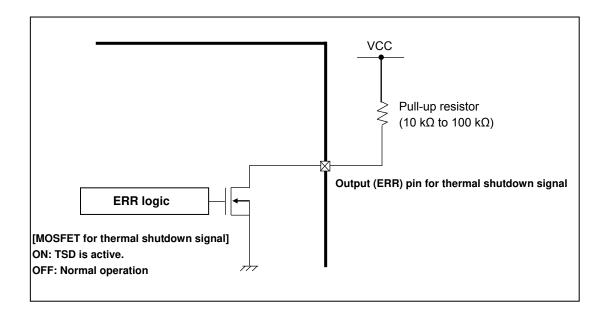
	Logic input				Output N	MOSFET		
IN1	IN2	IN3	IN4	OUT1 OUT2 OUT3 OUT				
L	L	L	L	Off	Off	Off	Off	
Н	L	L	L	On	Off	Off	Off	
L	Н	L	L	Off	On	Off	Off	
L	L	Н	L	Off	Off	On	Off	
L	L	L	Н	Off	Off	Off	On	
Н	Н	Н	Н	On	On	On	On	

# Output pin for thermal shutdown detection signal (ERR output function)

ERR	Function
Н	Normal operation
L	Thermal shutdown detection (TSD): active

Note: ERR pin is the Nch MOS output pin of open drain type. When using this function, please pull up the voltage level of the ERR pin to VCC. It is in the Hi-Z state (internal MOS = OFF) in the normal operation. It outputs low (internal MOS = ON) when the thermal shut down detection (TSD) is active.

When the thermal shutdown detection is cleared, the ERR pin outputs high level again (internal MOS = OFF). Moreover, when the ERR pin is not used, please leave this pin open.





# Absolute Maximum Ratings (Ta=25°C)

Characteristics	Symbol	Rating	Unit
Motor power supply VM	VM (max)	45	V
Difference voltage between VM and COM	VDIFF (max)	45	V
Motor output voltage	VOUT (max)	80	V
Motor output current (per one channel)	IOUT (max)	1.5	А
Internal logic power supply	VCC (max)	6.0	V
Logic input veltage	VIN(H) (max)	6.0	V
Logic input voltage	VIN(L) (min)	-0.4	V
ERR output pin voltage range	VOD (max)	6.0	V
ERR output pin inflow current range	IOD (max)	20	mA
Dower discipation (standalone)	PD	1.47 (Note 1)	W
Power dissipation (standalone)	PD	2.7 (Note 2)	VV
Operating temperature	Topr	-20 to 85	°C
Storage temperature	Tstr	-55 to 150	°C
Junction temperature	Tj (max)	150	°C

Note 1: Standalone. When Ta exceeds 25°C, derating with 11.8 mW/°C is necessary.

Note 2: On PCB (size: 50 mm × 50 mm × 1.6 mm, Cu area: 50 %, single-side glass epoxy). When Ta exceeds 25°C, derating with 21.6 mW/°C is necessary.

## **Absolute maximum ratings**

The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating (s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion, including peripheral circuits and parts. The value of even one parameter of the absolute maximum ratings should not be exceeded under any circumstances. The device does not have overvoltage detection circuit. Therefore, the device is damaged if a voltage exceeding its rated maximum is applied. All voltage ratings, including supply voltages, must always be followed. The other notes and considerations described later should also be referred to.

#### Operation Ranges (Ta=-20 to 85°C)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Motor power supply VM	VM	_	10	_	40	٧
Motor output voltage	VOUT	_	0	_	80	٧
Motor output current	IOUT	Ta=25°C, per one channel	_	0.75	1.5	Α
Internal logic power supply voltage	VCC	_	4.75	5.0	5.25	٧
	VIN(H)	Logic input high level	2.0	_	5.5	V
Logic input voltage	VIN(L)	Logic input low level	0	_	0.8	٧

Note: Please use the device with extra margin regarding the absolute maximum ratings. Moreover, please pay attention to the thermal conditions enough during use.



# Electrical Characteristics 1 (Ta=25°C and VM=24 V, unless otherwise specified.)

Characteristics		Symbol	Test condition	Min	Тур.	Max	Unit
Logic input voltage		VIH	Logic input voltage High level (Note)		_	5.5	V
		VIL	Logic input voltage Low level (Note)	GND	_	0.8	V
Input hysteresis voltage	е	VIN(HYS)	Logic input pin (Note)	100	_	300	mV
Lagia input august	High	IIN(H)	Logic input voltage High level (VIN=3.3 V)	_	33	55	μΑ
Logic input current	Low	IIN(L)	Logic input voltage Low level (VIN=0 V)	_	_	1	μA
IM consumption current		IM	Output pins: open, in normal operation, motor output-stage operation		3.0	5.0	mA
Remaining voltage of ERR output		VOD(L)	IOD=10 mA	0	_	0.5	٧
Regenerative diode forward voltage		VFN	IOUT=1.5 A	0.9	1.1	1.5	٧
Output MOSFET OFF leakage current		lleak	VOUT=80 V, Output MOSFET: OFF	_	_	1	μΑ
Output MOSFET  Between drain and sou On-resistance	ırce	RON (D-S)	IOUT=1.5 A	_	0.25	0.35	Ω

Note: VIH is defined as the VIN voltage that causes the outputs to change when the voltage of the test pin is gradually raised from 0 V.

VIL is defined as the VIN voltage that causes the outputs to change when the voltage of the pin is then gradually lowered. The difference between VIL and VIH is defined as the input hysteresis(VIN(HYS)).

## Electrical Characteristics 2 (Ta=25°C and VM=24 V, unless otherwise specified.)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
VCC pin current	ICC	4.75 V≤VCC≤5.25 V	_	2.5	5.0	mA
Temperature threshold of thermal shutdown detection (TSD) (Note 1)	TjTSD	_	155	170	185	°C
VM recovery voltage	VMR	_	7.0	8.0	9.0	V
Over current detection (ISD) threshold (Note 2)	ISD	(Design value)	2.1	3.0	5.0	Α

#### Note 1: Thermal shutdown (TSD)

When the junction temperature of the IC reaches the TSD threshold, the TSD circuit operates and turns off the output transistors. Noise rejection blanking time is provided to avoid misdetection by switching. The IC operation recovers automatically after specified recovery time passes. The TSD circuit is a backup function to detect a thermal error, therefore it is not recommended to be used aggressively.

#### Note 2: Over-current detection (ISD)

When the output current reaches the threshold, the ISD circuit operates and turns off the output transistors. Noise rejection blanking time is provided to avoid misdetection by switching. The IC operation recovers automatically after specified recovery time passes.



# Cautions on over current detection (ISD) and thermal shutdown detection (TSD)

The ISD and TSD circuits are only intended to provide temporary protection against irregular conditions such as an output short-circuits; they do not necessarily guarantee the complete IC safety. If the device is used beyond the specified operating ranges, these circuits may not operate properly: then the device may be damaged due to an output short-circuit. The ISD circuit is only intended to provide a temporary protection against an output short-circuit. If such condition persists for a long time, the device may be damaged due to overstress. Overcurrent conditions must be removed immediately by external hardware.

## **Back-EMF**

While a motor is rotating, there is a timing at which power is fed back to the power supply. At that timing, the motor current recirculates back to the power supply due to the effect of the motor back-EMF. If the power supply does not have enough sink capability, the power supply and output pins of the device might rise above the rated voltages. The magnitude of the motor back-EMF varies with usage conditions and motor characteristics. It must be fully verified that there is no risk that the device or other components will be damaged or fail due to the motor back-EMF.

## IC mounting

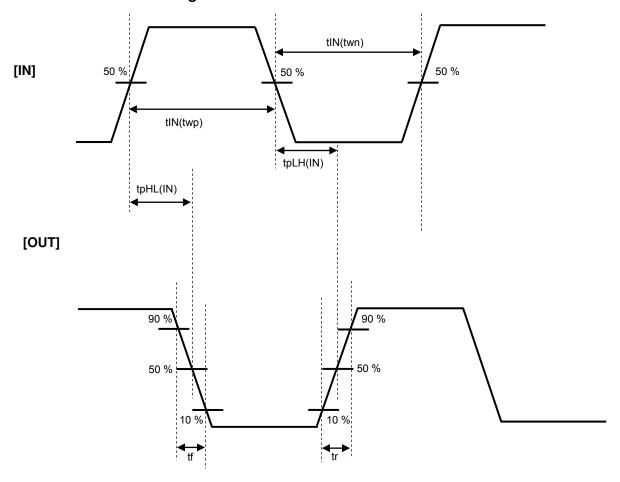
Do not insert devices incorrectly or in the wrong orientation. Otherwise, it may cause breakdown, damage and/or deterioration of the device.

# AC Electrical Characteristics (Ta=25°C and VM=24 V, unless otherwise specified.)

Characteristics	Symbol	Test condition	Min	Тур.	Max	Unit
Minimum pulse width of logic	tIN(twp)	(Design value)	1.0	_	_	μs
input	tIN(twn)	(Design value)	1.0	_	_	μs
Output MOSFET switching	tr	_	0.05	0.10	0.15	μs
characteristics	tf	_	0.05	0.10	0.15	μs
Output MOSFET response	tpLH(IN)	Between IN and OUT	0.20	0.70	1.20	μs
characteristics	tpHL(IN)	Between IN and OUT	0.20	0.70	1.20	μs
OSCS frequency	fOSCS	_	5120	6400	7680	kHz
Over current detection (ISD) masking time	tISD(mask)	fOSCS(=6.4 MHz)×8 clk	1.0	1.25	1.5	μs
Off time after over current detection (ISD)	_	_	260	320	390	μs
Thermal shutdown detection (TSD) masking time	tTSD(mask)	fOSCS(=6.4 MHz)×32 clk	4.0	5.0	6.0	μs
Off time after thermal shutdown detection (TSD)	_	_	260	320	390	μs



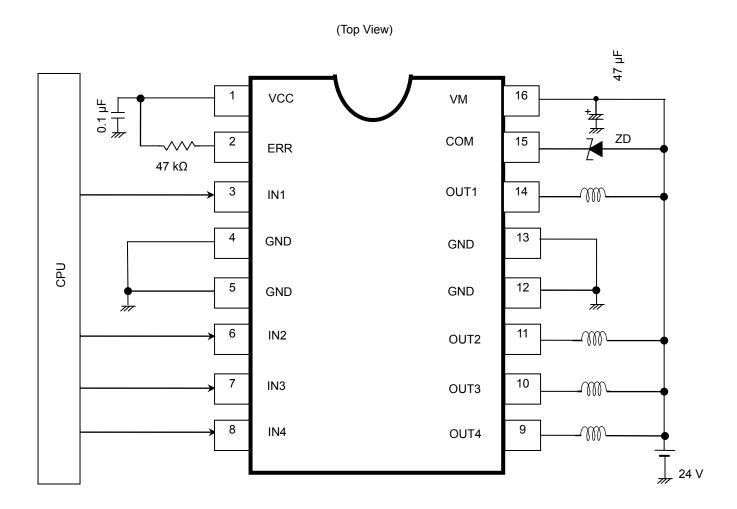
# **AC Characteristics Timing chart**



Timing charts may be simplified for explanatory purposes.



# **Application Circuit Example**



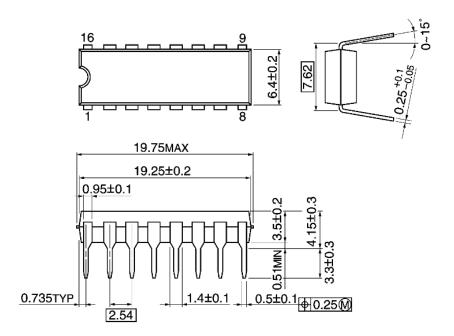
The application circuits shown in this document are provided for reference purposes only, and are not guaranteed for mass production.

As for zener diodes, recommended zener voltage is higher than VM.



# Package Dimensions DIP16-P-300-2.54A

Unit: mm



Weight: 1.11 g (typ.)



#### **Notes on Contents**

#### 1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

#### 2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

#### 3. Timing Charts

Timing charts may be simplified for explanatory purposes.

#### 4. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass-production design stage.

Providing these application circuit examples does not grant a license for industrial property rights.

## **IC Usage Considerations**

## Notes on handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in the case of overcurrent and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead to smoke or ignition. To minimize the effects of the flow of a large current in the case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition. Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly. Make sure that the positive and negative terminals of power supplies are connected properly.

  Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.

  In addition, do not use any device inserted in the wrong orientation or incorrectly to which current is applied even just once.
- (5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator.

  If there is a large amount of leakage current such as from input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure may cause smoke or ignition. (The overcurrent may cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection-type IC that inputs output DC voltage to a speaker directly.



# Points to remember on handling of ICs

#### **Overcurrent detection Circuit**

Overcurrent detection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the overcurrent detection circuits operate against the overcurrent, clear the overcurrent status immediately.

Depending on the method of use and usage conditions, exceeding absolute maximum ratings may cause the overcurrent detection circuit to operate improperly or IC breakdown may occur before operation. In addition, depending on the method of use and usage conditions, if overcurrent continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

#### **Thermal Shutdown Circuit**

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over-temperature, clear the heat generation status immediately.

Depending on the method of use and usage conditions, exceeding absolute maximum ratings may cause the thermal shutdown circuit to operate improperly or IC breakdown to occur before operation.

#### **Heat Radiation Design**

When using an IC with large current flow such as power amp, regulator or driver, design the device so that heat is appropriately radiated, in order not to exceed the specified junction temperature (Tj) at any time or under any condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, when designing the device, take into consideration the effect of IC heat radiation with peripheral components.

#### **Back-EMF**

When a motor rotates in the reverse direction, stops or slows abruptly, current flows back to the motor's power supply owing to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond the absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.



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